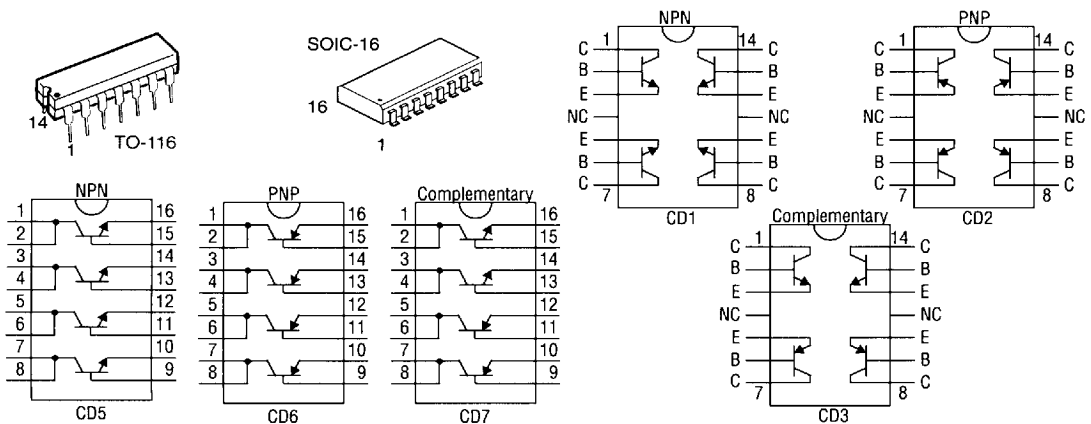


Multiple Bipolar Transistors—Quad

NATL SEMICOND (DISCRETE)

Device	Type	V_{CE} (V) Min	I_C (A) Max	$h_{FE} @ I_C$		f_T MHz Min	C_{ob} pF Max	$V_{CE(SAT)}$ Volts @ I_C/I_B & I_C			Config- uration	Package
				Min	mA			Max		mA		
MMPQ6502	BOTH	30	0.5	100	150	200	8	0.4	10	150	CD7	SOIC-16
MPQ6502	BOTH	30	0.5	100	150	200	8	0.4	10	150	CD3	TO-116
MMPQ6700	BOTH	40	0.2	70	10	200	4.5	0.25	10	1	CD7	SOIC-16
MPQ6700	BOTH	40	0.2	70	10	200	4.5	0.25	10	1	CD3	TO-116
MMPQ2369	NPN	15	0.5	40	10	450	4	0.25	10	10	CD5	SOIC-16
MPQ2369	NPN	15	0.5	40	10	450	4	0.25	10	10	CD1	TO-116
MMPQ2222	NPN	30	0.5	100	150	200	8	0.4	10	150	CD5	SOIC-16
MPQ2222	NPN	30	0.5	100	150	200	8	0.4	10	150	CD1	TO-116
MMPQ3724	NPN	36	1	35	500	300	12	0.32	10	300	CD5	SOIC-16
MPQ3724	NPN	36	1	35	500	300	12	0.32	10	300	CD1	TO-116
MMPQ3725	NPN	40	1	25	500	250	10	0.45	10	500	CD5	SOIC-16
MPQ3725	NPN	40	1	25	500	250	10	0.45	10	500	CD1	TO-116
MMPQ3904	NPN	40	0.2	75	10	250	4	0.2	10	10	CD5	SOIC-16
MPQ3904	NPN	40	0.2	75	10	250	4	0.2	10	10	CD1	TO-116
MMPQ2222A	NPN	40	0.5	100	150	200	8	0.3	10	150	CD5	SOIC-16
MMPQ2907	PNP	40	0.6	100	150	200	8	0.4	10	150	CD6	SOIC-16
MPQ2907	PNP	40	0.6	100	150	200	8	0.4	10	150	CD2	TO-116
MMPQ3467	PNP	40	1	40	500	175	25	0.5	10	500	CD6	SOIC-16
MPQ3467	PNP	40	1	40	500	175	25	0.5	10	500	CD2	TO-116
MMPQ3906	PNP	40	0.2	75	10	200	4.5	0.25	10	10	CD6	SOIC-16
MPQ3906	PNP	40	0.2	75	10	200	4.5	0.25	10	10	CD2	TO-116
MMPQ2907A	PNP	60	0.6	100	150	200	8	0.4	10	150	CD6	SOIC-16

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